## Supplementary Materials

## Theoretical design of dendrite-free zinc anode through intrinsic descriptors from symbolic regression

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Supplementary Figure 1. The correlation between the electronegativity and the charge transfer of doped atoms.


Supplementary Figure 2. The adsorption behavior of one Zn atom on four adsorbed sites. On most of doped surfaces (expect for surfaces doped with $\mathrm{Ga}, \mathrm{Ge}$, and Sn ), Zn atoms adsorbed on B and V sites will move towards the TD sites, proving that TD sites on these surfaces are the optimal adsorption sites.


Supplementary Figure 3. (A) The vertical growth trend of zinc nucleus on $\mathrm{Zn}(002)$ face; (B) the adsorption energy of vertical adsorption on doped-surfaces.


Supplementary Figure 4. The charge transition of the surface absorbed with single Zn atom and three atoms. (A) the firstly adsorbed Zn atom; (B) three adsorbed atoms and the numbers represent the sequence of adsorbed atoms.


Supplementary Figure 5. The absorption energy of single molecule and single Zn Atom on the doped surface.


Supplementary Figure 6. The relationship between the electronegativity of doping elements and the adsorption energy of single Zn atom on the doping surfaces.


Supplementary Figure 7. The relationship between the absolute value of the charge transfer of doping elements and the adsorption energy of single Zn atom on the doping surfaces.


Supplementary Figure 8. (A) The partial dependence plots of adsorption energy and ratio of radius; (B) the partial dependence plots of adsorption energy and d-band center.

Supplementary Table 1. The formation energy (eV) of doped surfaces and adsorption energy ( eV ) of different adsorption manners

| Doped <br> atom | $\boldsymbol{E}_{\text {doped }}$ | $\boldsymbol{u}_{\boldsymbol{x}}$ | $\boldsymbol{E}_{\boldsymbol{f}}$ | $\boldsymbol{E}_{\text {abl }}$ | $\boldsymbol{E}_{\text {ab2- } \boldsymbol{V}}$ | $\boldsymbol{E}_{\text {ab2-P }}$ |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| Al | -59.27 | -3.75 | -0.18 | -0.06 | -0.22 | -0.66 |
| Sc | -61.78 | -6.33 | -0.10 | -0.42 | -0.24 | -1.12 |
| Ti | -62.64 | -7.77 | 0.48 | -0.81 | -0.35 | -1.31 |
| V | -63.23 | -8.94 | 1.05 | -0.85 | -0.35 | -1.36 |
| Cr | -64.07 | -9.50 | 0.77 | -0.52 | -0.20 | -1.08 |
| Mn | -64.01 | -9.02 | 0.35 | -0.48 | -0.38 | -1.07 |
| Fe | -63.09 | -8.31 | 0.56 | -0.67 | -0.19 | -1.29 |
| Co | -62.16 | -7.11 | 0.29 | -0.90 | -0.46 | -1.56 |
| Ni | -61.35 | -5.57 | -0.44 | -0.53 | -0.45 | -1.22 |
| Cu | -59.32 | -3.72 | -0.26 | -0.32 | -0.01 | -1.01 |
| Ga | -58.53 | -2.91 | -0.28 | -0.06 | -0.29 | -0.75 |
| Ge | -59.61 | -4.49 | 0.22 | -0.23 | -0.26 | -0.78 |
| Ag | -58.57 | -2.83 | -0.40 | -0.13 | -0.22 | -0.73 |
| Cd | -56.59 | -0.45 | -0.80 | -0.04 | -0.19 | -0.56 |
| In | -58.10 | -2.55 | -0.21 | -0.24 | -0.21 | -0.77 |
| Sn | -59.21 | -3.83 | -0.03 | -0.22 | -0.16 | -0.53 |
| Pt | -62.86 | -6.06 | -1.46 | -0.47 | -0.52 | -1.03 |
| Au | -59.54 | -3.27 | -0.93 | -0.24 | -0.26 | -0.86 |
| Hg | -55.99 | -0.30 | -0.35 | -0.04 | -0.17 | -0.55 |
| Tl | -57.60 | -2.24 | -0.02 | -0.04 | -0.11 | -0.44 |
| Bi | -59.31 | -3.87 | -0.10 | -0.03 | -0.16 | -0.45 |
| Pb | -58.88 | -1.25 | -2.29 | -0.17 | -0.16 | -0.60 |
| Zn | -56.61 | -1.27 | 0.00 | -0.34 | -0.24 | -0.96 |

$E_{\text {doped }}$ is the energy of doped-surface; $u_{x}$ is the chemical potential in bulk phase of doped atom; $E_{f}$ is the formation energy of doped-surface; $E_{a b l}$ is the adsorption energy of the first adsorbed Zn atom; $E_{a d 2-v}$ is the adsorption energy of the second adsorbed Zn atom adsorbed vertically; $E_{\text {ad2-P }}$ is the adsorption energy of the second adsorbed Zn atom adsorbed parallelly.

Supplementary Table 2. The chemical potential (eV) of doped atoms in bulk phase

| Doped Atom | $\boldsymbol{E}_{\text {cell }}(\boldsymbol{\text { V V }}$ ) | $\boldsymbol{n}$ | $\boldsymbol{u}_{\boldsymbol{x}}(\boldsymbol{\text { eV }}$ ) |
| :--- | :--- | :--- | :--- |
| Al | -15.00 | 4 | -3.75 |
| Sc | -12.67 | 2 | -6.34 |
| Ti | -23.32 | 3 | -7.77 |
| V | -17.88 | 2 | -8.94 |
| Cr | -18.99 | 2 | -9.50 |
| Mn | -523.20 | 58 | -9.02 |
| Fe | -16.62 | 2 | -8.31 |
| Co | -14.22 | 2 | -7.11 |
| Ni | -22.28 | 4 | -5.57 |
| Cu | -14.88 | 4 | -3.72 |
| Ga | -23.25 | 8 | -2.91 |
| Ge | -35.94 | 8 | -4.49 |
| Ag | -25.45 | 9 | -2.83 |
| Cd | -3.65 | 4 | -0.91 |
| In | -22.94 | 9 | -2.55 |
| Sn | -30.68 | 8 | -3.84 |
| Pt | -24.23 | 4 | -6.06 |
| Au | -13.09 | 4 | -3.27 |
| Hg | -0.61 | 2 | -0.31 |
| Tl | -20.19 | 9 | -2.24 |
| Bi | -15.47 | 4 | -3.87 |
| Pb | -4.98 | 4 | -1.25 |
| Zn | -2.54 | 2 | -1.27 |

Supplementary Table 3. The date set of machine learning ${ }^{[1]}$

| Doped atom | $R$ | $n$ | $I(\mathrm{KJ} / \mathrm{mol})$ | $A(\mathrm{KJ} / \mathrm{mol})$ | $\chi$ | $\varepsilon_{d}(\mathrm{eV})$ | $E_{\text {ad }}(\mathrm{eV})$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Sc | 1.197 | 3 | 629.904 | 18.048 | 1.36 | -2.362 | -0.415803 |
| In | 1.219 | 3 | 555.4944 | 28.8 | 1.78 | -3.784 | -0.235524 |
| Cu | 0.934 | 11 | 741.7344 | 118.56 | 1.9 | -2.959 | -0.322977 |
| Ag | 1.051 | 11 | 727.3152 | 124.992 | 1.93 | -4.785 | -0.134702 |
| Pt | 1.015 | 10 | 860.0448 | 204.288 | 2.2 | -2.976 | -0.469616 |
| Bi | 1.328 | 4 | 699.408 | 90.466752 | 1.9 | -3.591 | -0.027704 |
| Ti | 1.073 | 4 | 655.4976 | 7.584 | 1.54 | -1.651 | -0.806733 |
| Fe | 0.920 | 8 | 758.6304 | 14.496 | 1.83 | -1.233 | -0.668427 |
| Ga | 1.117 | 3 | 575.9328 | 41.28 | 1.81 | -4.033 | -0.059575 |
| Cd | 1.109 | 12 | 863.4048 | 0 | 1.69 | -8.808 | -0.043195 |
| Au | 1.051 | 11 | 885.648 | 221.62848 | 2.4 | -4.494 | -0.239012 |
| Pb | 1.277 | 5 | 712.0032 | 34.944 | 1.8 | -3.423 | -0.165125 |
| V | 0.985 | 5 | 647.6352 | 50.4 | 1.63 | -1.102 | -0.854681 |
| Co | 0.912 | 9 | 756.576 | 63.552 | 1.88 | -0.946 | -0.904391 |
| Ge | 0.890 | 4 | 758.3424 | 118.34035 | 2.01 | -3.666 | -0.228384 |
| Mn | 1 | 7 | 713.664 | -50 | 1.55 | -1.448 | -0.483827 |
| Hg | 1.131 | 12 | 1002 | 0 | 1.9 | -4.494 | -0.037000 |
| Tl | 1.248 | 3 | 586.3872 | 36.192 | 1.8 | -7.211 | -0.040796 |
| Cr | 0.942 | 6 | 649.584 | 63.936 | 1.66 | -1.475 | -0.517165 |
| Ni | 0.9124 | 10 | 733.4304 | 110.976 | 1.91 | -1.472 | -0.525084 |
| Pd | 1 | 10 | 800.3424 | 53.952 | 2.2 | -2.74 | -0.477816 |
| Sn | 1.153 | 4 | 705.0144 | 106.75843 | 1.96 | -3.884 | -0.218760 |

$R$ is the ratio of the radius of doped atoms to that of Zn atom; $n$ is the number of valence electrons; $I$ is the first ionization energy of the doped elements; $A$ is the first affinity energy of the doped elements; $\chi$ is the electronegativity; $\varepsilon_{d}$ is the d-band center of doped surface; and $E_{a d}$ is the adsorption energy of single Zn atom on the doped-surface.

Supplementary Table 4. The formula for calculating adsorption energy obtained by symbolic regression method

The formula obtained after regression:

$$
\begin{aligned}
& E_{a d 1}=\left(\left(c_{1} \cdot R+\left(\left(c_{1} \cdot R\right)^{3}+\frac{\left(\left(\mathrm{c}_{2} A\right)^{1 / 3}+c_{3}\right)}{c_{4} \cdot \varepsilon_{d}}\right)\right.\right. \\
&\left.\left.\cdot\left(c_{5} \cdot \chi+\frac{\left(c_{1} \cdot \varepsilon_{d}\right)^{1 / 3} \cdot c_{7}}{\left(c_{3} \cdot R\right)^{3} \cdot c_{9}+c_{10}}+c_{11}\right)\right) \cdot\left(c_{12} \cdot R\right)^{3} \cdot c_{13}+c_{14}\right)
\end{aligned}
$$

| Constant | value | Constant | value |
| :--- | :--- | :--- | :--- |
| $\mathrm{C}_{1}$ | 0.95328 | $\mathrm{C}_{8}$ | 0.85266 |
| $\mathrm{C}_{2}$ | -0.389 | $\mathrm{C}_{9}$ | -1 |
| $\mathrm{C}_{3}$ | -17.057 | $\mathrm{C}_{10}$ | 0.77396 |
| $\mathrm{C}_{4}$ | -2.9882 | $\mathrm{C}_{11}$ | -18.266 |
| $\mathrm{C}_{5}$ | -2.9887 | $\mathrm{C}_{12}$ | 0.95328 |
| $\mathrm{C}_{6}$ | -0.27416 | $\mathrm{C}_{13}$ | -0.007802 |
| $\mathrm{C}_{7}$ | -0.088845 | $\mathrm{C}_{14}$ | -0.095742 |

## REFERENCES

1. Lide $\mathrm{DR}, \mathrm{CRC}$ handbook of chemistry and physics. CRC press, 2004.
